

Autonomous Audio Headset Switch with Reduced GND Switch R_{ON} and FM Capability

Check for Samples: [TS3A226E](#)

FEATURES

- Ground FET Switches (60mΩ typical)
- Autonomous Detection of Headset Types: 3-Poles or 4-Poles (with MIC on SLEEVE or RING2)
- Microphone Line Switches
- Supports FM Signal Transmission Through the Ground FETs
- Reduction of Click/Pop Noise
- VDD Range: 2.6 V – 4.7 V
- THD (Mic): 0.002% Typical
- Low Current Consumption: 6.5-μA Typical
- ±8kV Contact Discharge (IEC 61000-4-2) ESD Performance on SLEEVE and RING2 Pins

APPLICATIONS

- Mobile Phones / Tablet PCs
- Notebook/Ultrabook Computers

DESCRIPTION

The TS3A226E is an audio headset switch that detects 3- or 4-pole 3.5mm accessories. For a 4-pole accessory with a microphone, the TS3A226E also detects the MIC location and routes the microphone and ground signals automatically. The ground signal is routed through a pair of low-impedance ground FETs (60mΩ typical), resulting minimal impact on audio cross-talk performance. The autonomous detection feature allows end users to plug in accessories with different audio pole configurations into the mobile device and have them operate properly with no added software control and complexity. The ground FETs of the device are designed to allow FM signal pass-through, making it possible to use the ground line of the headset as an FM antenna in mobile audio application.

The TS3A226E is packaged within a 1.2mm × 1.2mm WCSP package, making it suitable for use in mobile application.

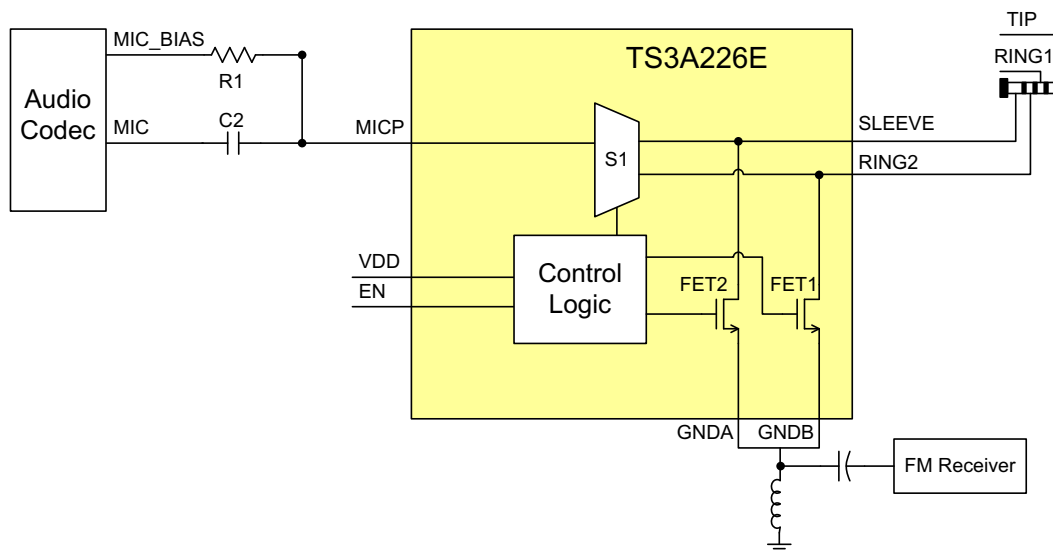


Figure 1. Typical Application Diagram

ORDERING INFORMATION

T _A	PACKAGE ⁽¹⁾⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	YFF- WCSP	Tape and reel	TS3A226EYFFR	YP226E

(1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

(2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.



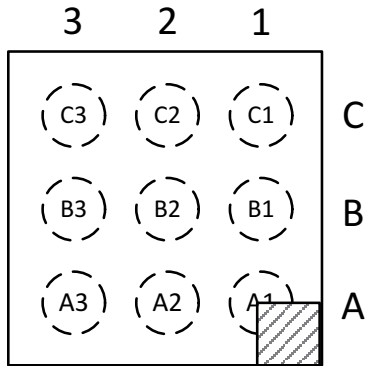
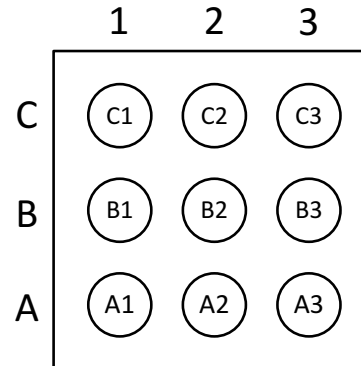
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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

PACKAGE; YFF-WCSP**Top View/Footprint****Bump View****Die Size: 1.2mm ×1.2mm****Bump Size: 0.25mm****Bump Pitch: 0.4mm****TS3A226E Pin Mapping (Top View)**

	3	2	1
C	GND	TIP	EN
B	SLEEVE	GNDA	MICp
A	RING2	GNDB	VDD

PIN FUNCTIONS

PIN			DESCRIPTION
NUMBER	NAME	TYPE	
A1	VDD	Supply	Power supply for the chip.
A2	GNDB	Ground	FET2 ground reference.
A3	RING2	I/O	Connected to the RING2 segment of the jack. The pin will be routed automatically by TS3A226E to either MICp or GNDB depending on the type of accessory.
B1	MICp	I/O	Microphone signal connection to codec. Microphone bias should be fed into this pin.
B2	GNDA	Ground	FET1 ground reference.
B3	SLEEVE	I/O	Connected to the SLEEVE segment of the jack. The pin will be routed automatically by TS3A226E to either MICp or GNDA depending on the type of accessory.
C1	EN	Input	A rising edge triggers the detection sequence. This pin can be connected to the headset jack to allow automatic pull-up to supply after headset insertion.
C2	TIP	I/O	Connected to the TIP segment of the headphone jack.
C3	GND	Ground	Chip ground reference.

S1 MUX DETAIL

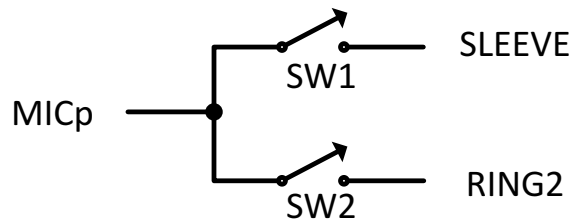


Figure 2. S1 Mux Detail

FUNCTIONAL TABLES: INTERNAL SWITCHES

EN	Accessory Type	Accessory Configuration	SW1	SW2	FET1	FET2
0	N/A	—	High Z	High Z	High Z	High Z
1	TRS 3-pole Headphone or Speaker	TIP = Audio Left Ring = Audio Right Sleeve = Ground	High Z	High Z	On	On
1	TRRS 4-pole Headphone	TIP = Audio Left Ring1 = Audio Right Ring2 = Ground Sleeve = Microphone	On	High Z	High Z	On
1	TRRS 4-pole Headphone	TIP = Audio Left Ring1 = Audio Right Ring2 = Microphone Sleeve = Ground	High Z	On	On	High Z
1	N/A	—	High Z	High Z	High Z	High Z

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		VALUE	UNIT
V _I	Voltage range on VDD ⁽²⁾	–0.3 to 5	V
	Voltage range on EN, MICP, RING2, SLEEVE, TIP ⁽²⁾	–0.3 to V _{DD} +0.5	V
T _A	Operating ambient temperature range ⁽³⁾	–40 to 85	°C
T _{J (MAX)}	Maximum operating junction temperature	125	°C
T _{stg}	Storage temperature range	–65 to 150	°C
ESD rating	Machine model (JESD 22 A115)	100	V
	Charge device model (JESD 22 C101)	500	V
	Human body model (JESD 22 A114)	2	kV
	Contact discharge on RING2, SLEEVE, TIP (IEC 61000-4-2)	8	kV

- (1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to network ground terminal.
- (3) In applications where high power dissipation and/or poor package thermal resistance is present, the maximum ambient temperature may have to be derated. Maximum ambient temperature [T_{A(max)}] is dependent on the maximum operating junction temperature [T_{J(max)}], the maximum power dissipation of the device in the application [P_{D(max)}], and the junction-to-ambient thermal resistance of the part/package in the application (θ_{JA}), as given by the following equation: T_{A(max)} = T_{J(max)} – (θ_{JA} × P_{D(max)})

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RECOMMENDED OPERATING CONDITIONS

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V _{DD}	Supply voltage range	2.6	4.5	V
V _{IO}	Input/Output voltage range (EN, MICP, RING2, SLEEVE, TIP)	0	V _{DD}	V
V _{IH}	Input Logic High for EN	VDD = 2.6 V	1.16	V _{DD}
		VDD = 3.3 V	1.24	V _{DD}
		VDD = 4.5 V	1.48	V _{DD}
V _{IL}	Input Logic Low for EN	VDD = 2.6 V	0	0.19
		VDD = 3.3 V	0	0.3
		VDD = 4.5 V	0	0.5
T _A	Operating temperature range	–40	85	°C

KEY ELECTRICAL CHARACTERISTICS

Unless otherwise noted the specification applies over the V_{DD} range and operating junction temperature –40°C ≤ T_A ≤ 70°C. Typical values are for V_{DD} = 3.3V and T_J = 25°C.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{DD}	Input Voltage Range		2.6	3.3	4.5	V
I _{DD}	Quiescent Current	V _{DD} = 4.5 V, V _{MICp} = 1.8 V to V _{DD}		6.5	14	μA
SWITCH RESISTANCE						
R _{F1}	FET1 On Resistance	V _{DD} = 2.6 V, V _{GND} = 0 V, I _{GND} = 10 mA		60	85	mΩ
R _{F2}	FET2 On Resistance			60	85	
R _{SW1}	SW1 On Resistance	V _{DD} = 2.6 V, V _{SLEEVE/RING2} = 0 V to 2.6 V, I _{MIC} = ±10 mA			10.5	Ω
R _{SW2}	SW2 On Resistance				10.5	
SWITCH LEAKAGE CURRENT						
I _{OFF-0.1}	FET1 and FET2 off leakage	V _{IN} = 0 V to 2.6 V, V _{OUT} = 0 V, V _{DD} = 4.5 V			1	μA
I _{OFF-10}	SW1, SW2 off leakage				1	
I _{ON-10}	SW1, SW2 on leakage				1	
SWITCH DYNAMIC CHARACTERISTICS						
BW _{F1}	FET1 Bandwidth	V = 60 mV _{PP} , I _{bias} = 10 mA		160	200	MHz
BW _{F2}	FET2 Bandwidth			160	200	
PSR ₂₁₇	Power Supply Rejection, R _L = 50 Ω	V = 200 mV _{PP} , f = 217 Hz		–110		dB
PSR _{1k}		V = 200 mV _{PP} , f = 1 kHz		–100		dB
PSR _{20k}		V = 200 mV _{PP} , f = 20 kHz		–85		dB
ISO _{S1}	SLEEVE or RING2 to MICP Isolation	V = 200 mV _{PP} , f = 20 kHz, R _L = 50 Ω		–80		dB
SEP _{S1}	SLEEVE to RING2 Separation	V = 200 mV _{PP} , f = 20 kHz, R _L = 50 Ω (see Figure 5)		–80		dB
THD ₁₀	Total Harmonic Distortion	V = 10 mV _{PP} , f = 20-20 kHz, R _S = 600 Ω		0.01%		
THD ₂₀₀		V = 200 mV _{PP} , f = 20-20 kHz, R _S = 600 Ω		0.002%		

TYPICAL CHARACTERISTICS

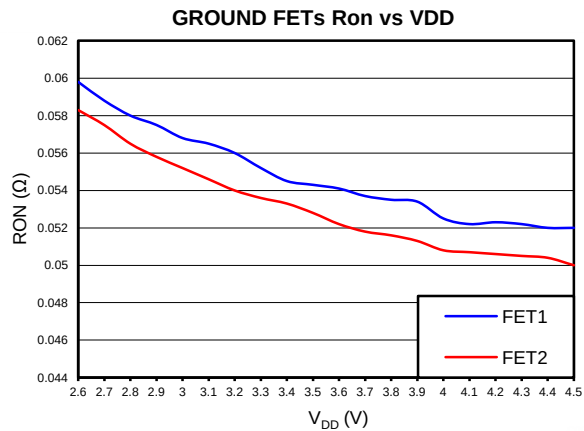


Figure 3.

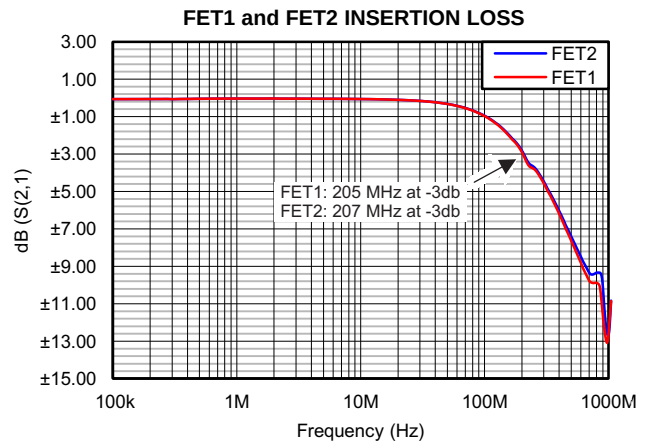


Figure 4.

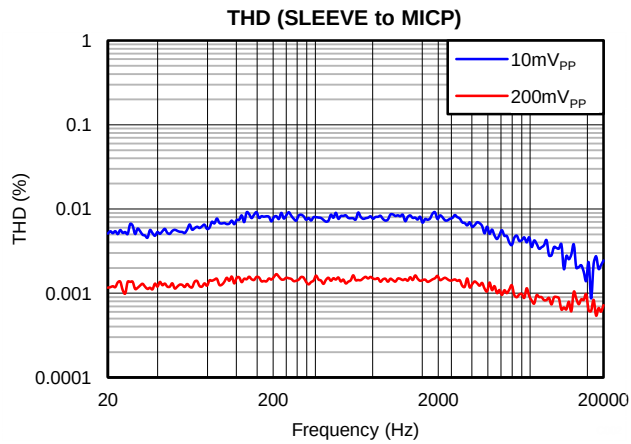


Figure 5.

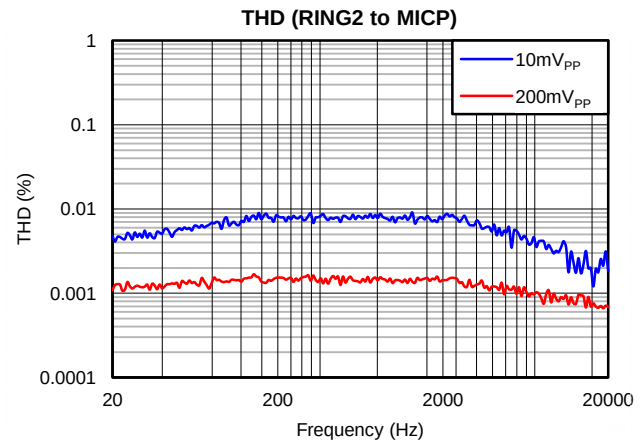


Figure 6.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TS3A226EYFFR	NRND	DSBGA	YFF	9	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	YP2 26E	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

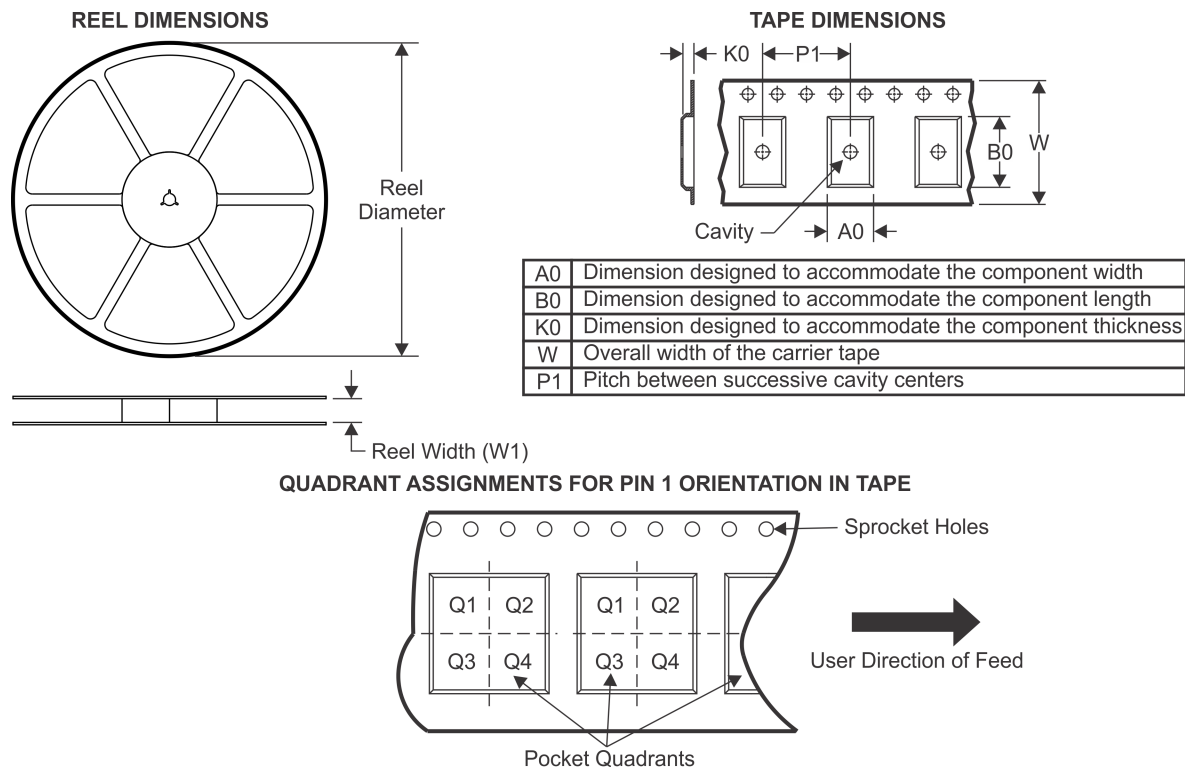
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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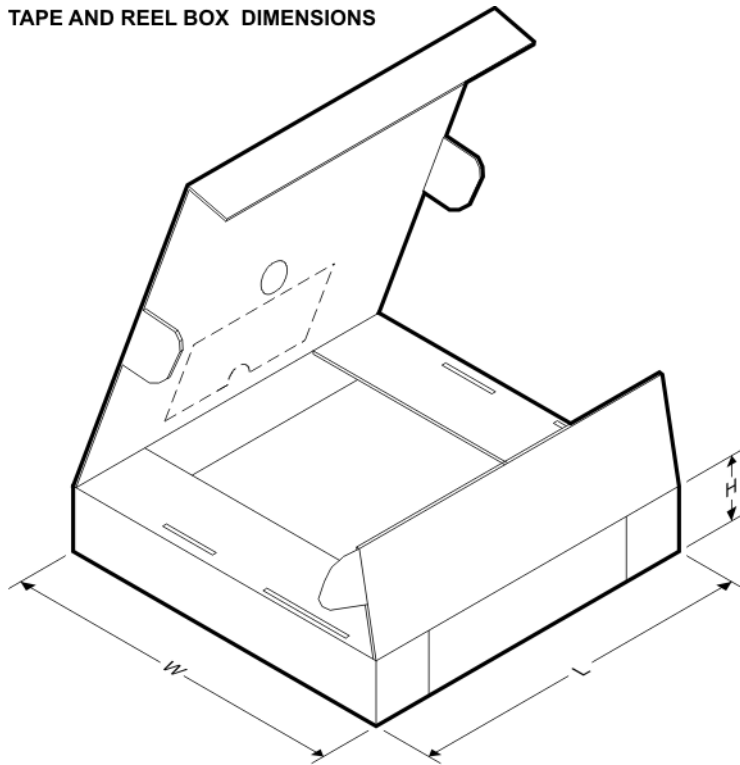
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TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS3A226EYFFR	DSBGA	YFF	9	3000	180.0	8.4	1.46	1.36	0.7	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS

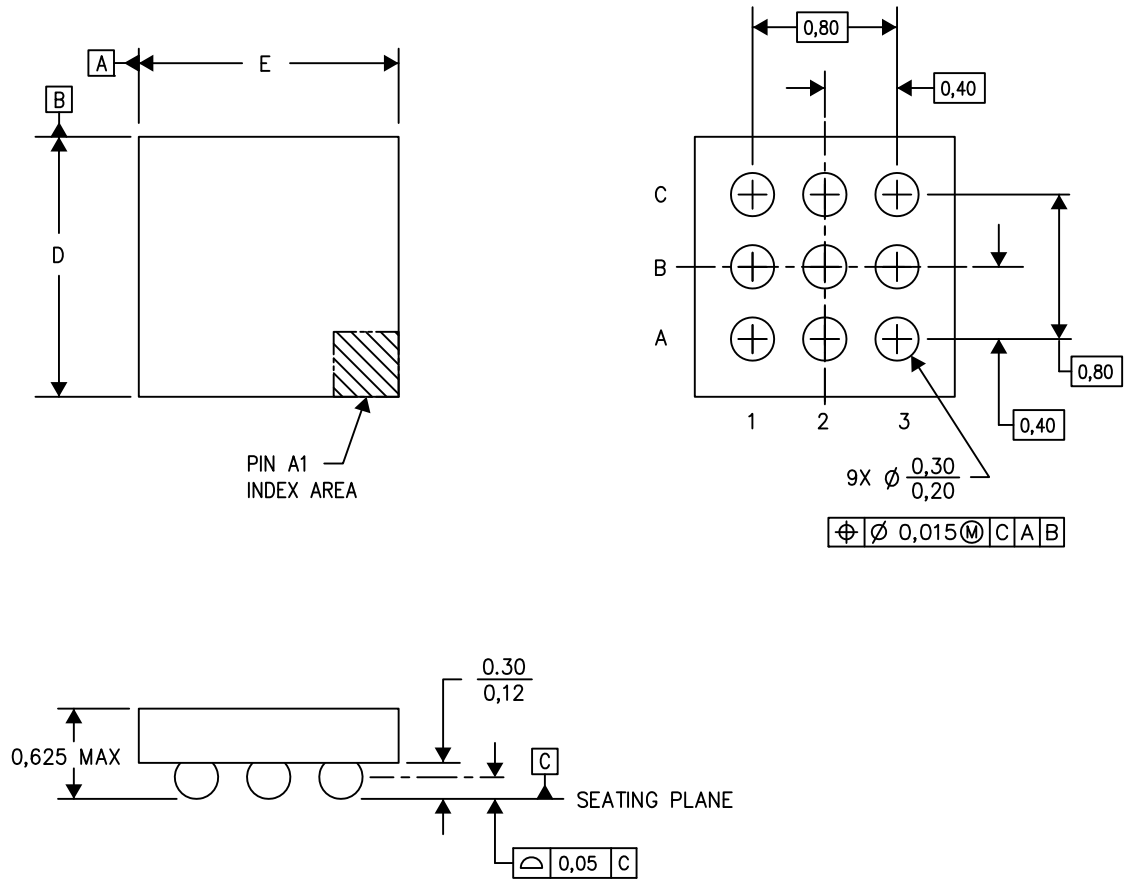


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS3A226EYFFR	DSBGA	YFF	9	3000	182.0	182.0	17.0

YFF (S-XBGA-N9)

DIE-SIZE BALL GRID ARRAY



D: Max = 1.386 mm, Min = 1.326 mm

E: Max = 1.286 mm, Min = 1.226 mm

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- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. NanoFree™ package configuration.

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